**Product data sheet** 

## 1. Product profile

### 1.1 General description

NPN low V<sub>CEsat</sub> Breakthrough In Small Signal (BISS) transistor, encapsulated in an ultra thin SOT1061 leadless small Surface-Mounted Device (SMD) plastic package with medium power capability.

PNP complement: PBSS5330PA.

#### 1.2 Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors
- Exposed heat sink for excellent thermal and electrical conductivity
- Leadless small SMD plastic package with medium power capability

### 1.3 Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	30	V
Ic	collector current		-	-	3	Α
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	5	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C = 3 \text{ A};$ $I_B = 300 \text{ mA}$	[ <u>1]</u> _	75	100	mΩ

[1] Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 





# 2. Pinning information

Table 2. Pinning

10010 21	9		
Pin	Description	Simplified outline	Graphic symbol
1	base		_
2	emitter	3	3 
3	collector	1 2 Transparent top view	1

# 3. Ordering information

Table 3. Ordering information

Type number	Package	Package		
	Name	Description	Version	
PBSS4330PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; three terminals; body 2 $\times$ 2 $\times$ 0.65 mm	SOT1061	

## 4. Marking

Table 4. Marking codes

Type number	Marking code
PBSS4330PA	AH

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

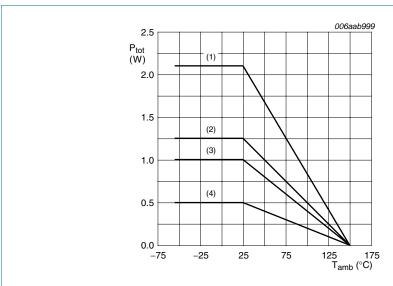
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	50	V
$V_{CEO}$	collector-emitter voltage	open base	-	30	V
$V_{EBO}$	emitter-base voltage	open collector	-	6	V
I <sub>C</sub>	collector current		-	3	Α
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	5	Α
I <sub>B</sub>	base current		-	500	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> -	500	mW
			[2] _	1	W
			[3] _	1.25	W
			[4] _	2.1	W

Table 5. Limiting values ... continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		<b>–55</b>	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



- (1) Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint
- (2) FR4 PCB, mounting pad for collector 6 cm<sup>2</sup>
- (3) FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>
- (4) FR4 PCB, standard footprint

Fig 1. Power derating curves

### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$ thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	250	K/W	
		[2]	-	125	K/W	
		[3]	-	100	K/W	
			[4]	-	60	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- 3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

PBSS4330PA\_1

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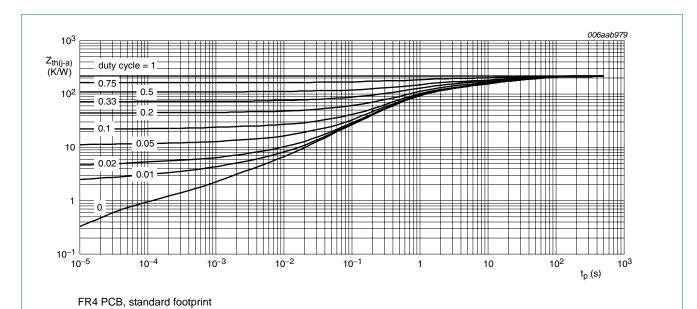
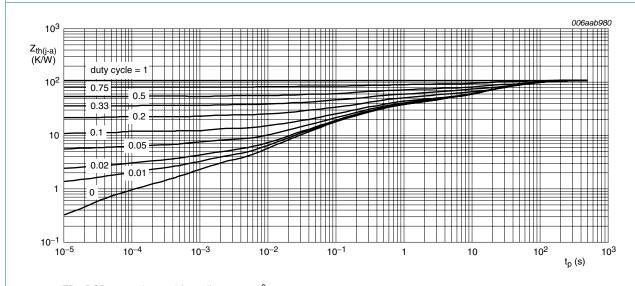


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

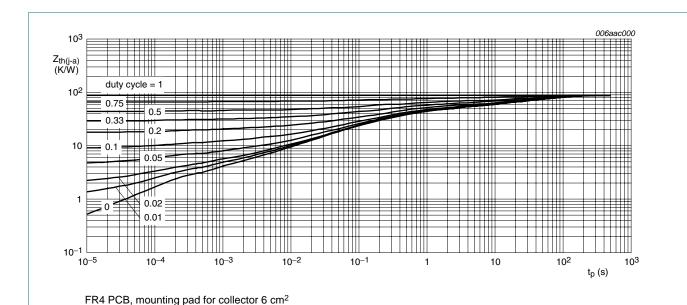
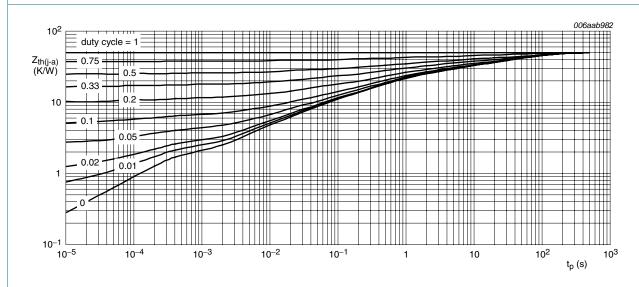


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

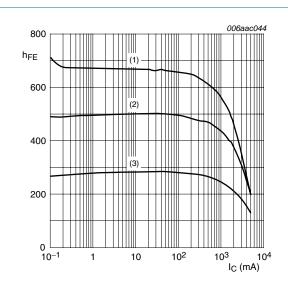
## 7. Characteristics

**Table 7. Characteristics** 

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nΑ
	cut-off current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	50	μА
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; V_{BE} = 0 \text{ V}$	-	-	100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V	<u>[1]</u>			
		$I_C = 0.5 A$	300	465	-	
		I <sub>C</sub> = 1 A	270	435	700	
		I <sub>C</sub> = 2 A	230	370	-	
		I <sub>C</sub> = 3 A	180	310	-	
V <sub>CEsat</sub> collector-emitter saturation voltage		$I_C = 0.5 \text{ A}; I_B = 50 \text{ mA}$	<u>[1]</u> -	40	60	mV
	saturation voltage	$I_C = 1 A; I_B = 50 mA$	<u>[1]</u> -	80	110	mV
		$I_C = 2 A$ ; $I_B = 100 \text{ mA}$	<u>[1]</u> -	155	220	mV
		$I_C = 3 A$ ; $I_B = 300 \text{ mA}$	<u>[1]</u> -	220	300	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C = 3 A; I_B = 300 \text{ mA}$	[1] -	75	100	mΩ
V <sub>BEsat</sub>	base-emitter	$I_C = 2 A$ ; $I_B = 100 \text{ mA}$	<u>[1]</u> -	0.95	1.1	V
	saturation voltage	$I_C = 3 A$ ; $I_B = 300 \text{ mA}$	<u>[1]</u> -	1.07	1.2	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE} = 2 \text{ V}; I_{C} = 1 \text{ A}$	[1] -	0.76	1	V
t <sub>d</sub>	delay time	$V_{CC} = 9 \text{ V}; I_C = 2 \text{ A};$	-	11	-	ns
t <sub>r</sub>	rise time	$I_{Bon} = 0.1 \text{ A};$	-	52	-	ns
t <sub>on</sub>	turn-on time	$I_{Boff} = -0.1 A$	-	63	-	ns
ts	storage time		-	230	-	ns
t <sub>f</sub>	fall time		-	40	-	ns
t <sub>off</sub>	turn-off time		-	270	-	ns
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 100 \text{ mA};$ f = 100 MHz	100	210	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz	-	21	30	pF

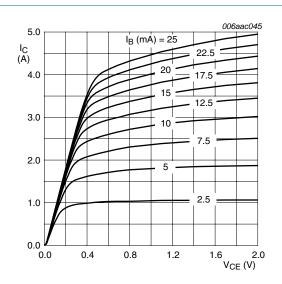
<sup>[1]</sup> Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 



 $V_{CE} = 2 V$ 

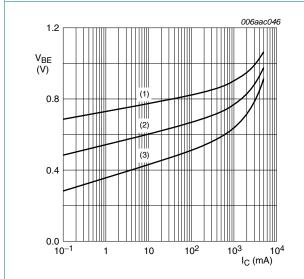
- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

Fig 6. DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

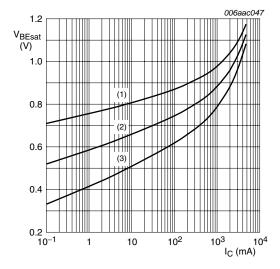
Fig 7. Collector current as a function of collector-emitter voltage; typical values





- (1)  $T_{amb} = -55 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = 100 \, ^{\circ}C$

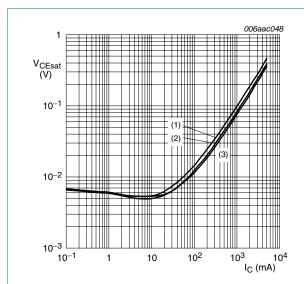
Fig 8. Base-emitter voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$ 

- (1)  $T_{amb} = -55 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = 100 \, ^{\circ}C$

Fig 9. Base-emitter saturation voltage as a function of collector current; typical values



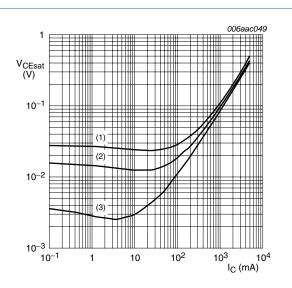
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values

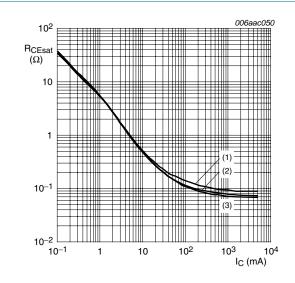


(1) 
$$I_C/I_B = 100$$

(2) 
$$I_C/I_B = 50$$

(3)  $I_C/I_B = 10$ 

Fig 11. Collector-emitter saturation voltage as a function of collector current; typical values



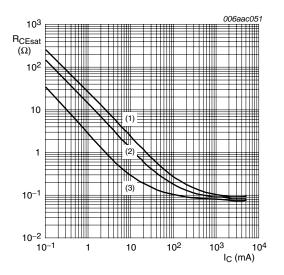
$$I_{\rm C}/I_{\rm B}=20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig 12. Collector-emitter saturation resistance as a function of collector current; typical values



(1) 
$$I_C/I_B = 100$$

(2)  $I_C/I_B = 50$ 

(3)  $I_C/I_B = 10$ 

Fig 13. Collector-emitter saturation resistance as a function of collector current; typical values

## 8. Test information

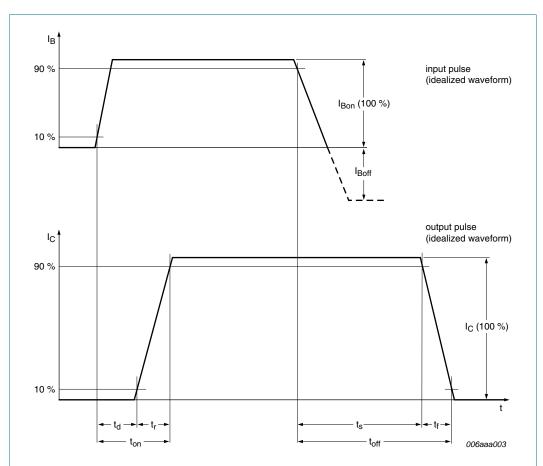
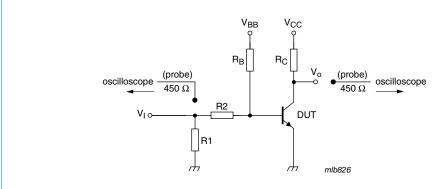


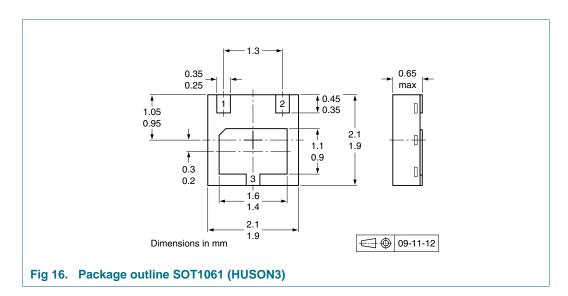
Fig 14. BISS transistor switching time definition



 $V_{CC}$  = 9 V;  $I_{C}$  = 2 A;  $I_{Bon}$  = 0.1 A;  $I_{Boff}$  = -0.1 A

Fig 15. Test circuit for switching times

# 9. Package outline



# 10. Packing information

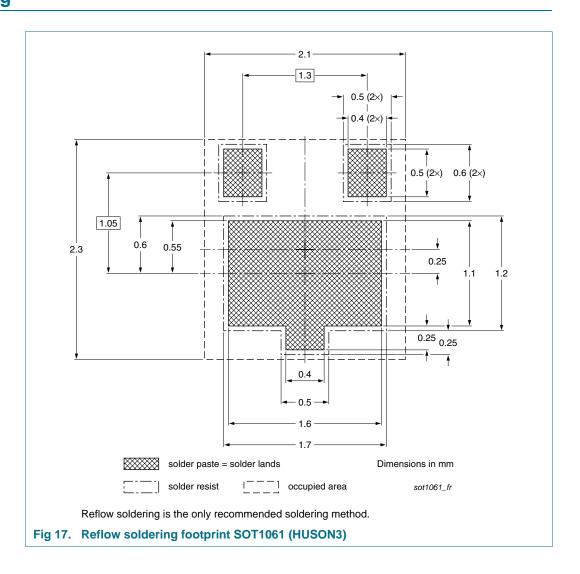
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			3000
PBSS4330PA	SOT1061	4 mm pitch, 8 mm tape and reel	-115

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

# 11. Soldering



# 12. Revision history

#### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4330PA_1	20100419	Product data sheet	-	-

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# 15. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information
4	Marking 2
5	Limiting values
6	Thermal characteristics 3
7	Characteristics 6
8	Test information9
9	Package outline
10	Packing information 10
11	Soldering
12	Revision history
13	Legal information
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks14
14	Contact information 14
15	Contents

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